Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type

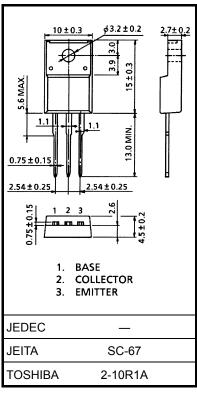
2SD2257

High-Power Switching Applications
Hammer Drive, Pulse Motor Drive Applications

- High DC current gain: $h_{FE} = 2000$ (min)
- Low saturation voltage: $V_{CE (sat)} = 1.5 \text{ V (max)}$
- Complementary to 2SB1495

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	100	V	
Collector-emitter voltage		V _{CEO}	100	V	
Emitter-base voltage		V _{EBO}	8	V	
Collector current	DC	IC	±3	Α	
	Pulse	I _{CP}	±5		
Base current		Ι _Β	0.3	Α	
Collector power dissipation	Ta = 25°C	D.	2.0	W	
	Tc = 25°C	P _C	20		
Junction temperature		Тј	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



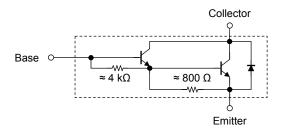
Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

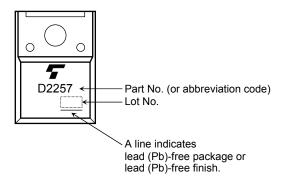
Equivalent Circuit

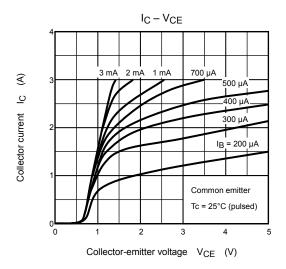


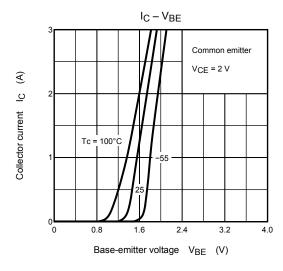
Electrical Characteristics (Tc = 25°C)

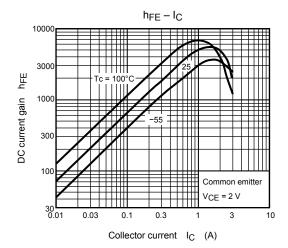
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 100 V, I _E = 0	_	_	10	μΑ
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0	0.8	_	4.0	mA
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	100	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 2 V, I _C = 1 A	2000	_	_	
		h _{FE} (2)	V _{CE} = 2 V, I _C = 2 A	2000	_	_	
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 1.5 A, I _B = 1.5 mA	_	_	1.5	V
Base-emitter saturation voltage		V _{BE} (sat)	I _C = 1.5 A, I _B = 1.5 mA	_	_	2.0	V
Emitter-collector forward voltage		V _{ECF}	I _E = 1 A, I _B = 0	_	_	2.0	V
Switching time	Turn-on time	t _{on}	Output 20 μ s Input N N N N N N N N N N N N N	_	0.5	_	
	Storage time	t _{stg}		1	2.0	_	μs
	Fall time	t _f			0.5	_	

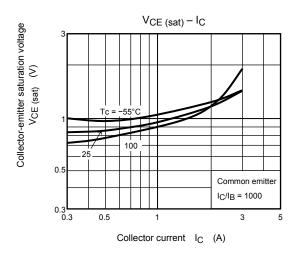
Marking

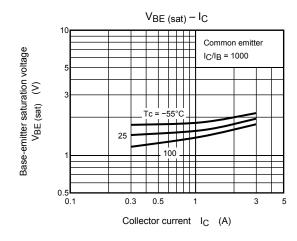


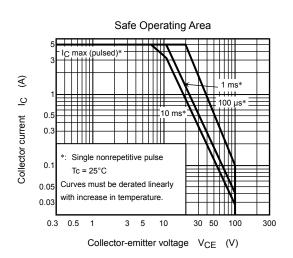












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RESTRICTIONS ON PRODUCT USE

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